


	<h2 style="color: #E67E22;">SI1012CR-T1-GE3</h2>
 <p>Image may be representation. See specs for product details.</p>	<b>Hersteller-Teilenummer:</b> <a href="#">SI1012CR-T1-GE3</a>
	<b>Hersteller / Marke:</b> <a href="#">Vishay / Siliconix</a>
	<b>Teil der Beschreibung:</b> MOSFET N-CH 20V 0.63A SC-75A
	<b>Datenblätter:</b>  <a href="#">SI1012CR-T1-GE3.pdf</a>
	<b>RoHs Status:</b> Bleifrei / RoHS-konform
	<b>Lagerzustand:</b> New original, 87625 pcs Stock Available.
<b>Liefern von:</b> Hong Kong	
<b>Versandweg:</b> DHL/Fedex/TNT/UPS/EMS	

### Spezifikationen

Teilenummer	SI1012CR-T1-GE3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 0.63A SC-75A
Kategorie	<a href="#">Diskrete Halbleiterprodukte</a> > <a href="#">Transistoren-FETs</a> ,
Teilstatus	87625 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-75, SOT-416
Supplier Device-Gehäuse	SC-75A
Verlustleistung (max)	240mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	-
Rds On (Max) @ Id, Vgs	396 mOhm @ 600mA, 4.5V
VGS (th) (Max) @ Id	1V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	2nC @ 8V
Eingabekapazität (Ciss) (Max) @ Vds	43pF @ 10V
Antriebsspannung (Max Rds On, Min Rds On)	1.5V, 4.5V
Vgs (Max)	±8V
Verpackung	Tape & Reel (TR)












SI1012CR-T1-GE3 ist neu im Original, Suche SI1012CR-T1-GE3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1012CR-T1-GE3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI1012CR-T1-GE3: [Info@Y-IC.com](mailto:Info@Y-IC.com)

Sie können auch interessiert sein:

 <p><b>SI1012R</b> VISHAY SI1012R VISHAY</p>	 <p><b>SI1012CR</b> VISHAY VISHAY SC75A</p>	 <p><b>SI1012CR-T1-GE3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 20V 0.63A SC-75A</p>	 <p><b>SI1012-A-GMR</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 42-WFQFN</p>
 <p><b>SI1012-TP</b> Micro Commercial Components (MCC) N-CHANNEL MOSFET, SOT-523 PACKAG</p>	 <p><b>SI1012-C-GM2R</b> Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM&lt;1GHZ 42-VFLGA</p>	 <p><b>SI1012R-T1-E3</b> Vishay / Siliconix MOSFET N-CH 20V 500MA SC-75A</p>	 <p><b>SI1012R-T1-E3</b> Electro-Films (EFI) / Vishay MOSFET N-CH 20V 500MA SC-75A</p>

### heiße Teile

Mehr

 SI1000-C-GM	 SI1002-C-GMR	 SI1003-C-GM	 SI1011X-T1-GE3	 SI1011X-T1-GE3
 SI1012CR-T1-GE3	 SI1012R-T1	 SI1012R-T1-E3	 SI1012R-T1-E3	 SI1012R-T1-GE3
 SI1012R-T1-GE3	 SI1012X-T1	 SI1012X-T1-E3	 SI1012X-T1-E3	 SI1012X-T1-GE3
 SI1012X-T1-GE3	 SI1013CX-T1-GE3	 SI1013CX-T1-GE3	 SI1013R-T1	 SI1013R-T1-E3
 SI1013R-T1-E3	 SI1013R-T1-GE3	 SI1013R-T1-GE3	 SI1013X-T1	 SI1013X-T1-E3
 SI1013X-T1-E3	 SI1013X-T1-GE3	 SI1013X-T1-GE3	 SI1016CX-T1-GE3	 SI1016CX-T1-GE3
 SI1016X-T1-E3	 SI1016X-T1-E3	 SI1016X-T1-GE3	 SI1016X-T1-GE3	 SI1016X2-T1-GE3
 SI1021R-T1	 SI1021R-T1-E3	 SI1021R-T1-E3	 SI1022R-T1	 SI1022R-T1-E3
 SI1022R-T1-E3	 SI1022R-T1-GE3	 SI1022R-T1-GE3	 SI1022R-T1-E3	 SI1023CX-T1-GE3
 SI1023CX-T1-GE3	 SI1023X-T1	 SI1023X-T1-E3	 SI1023X-T1-E3	 SI1023X-T1-GE3

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